

### NPN medium power transistors

#### **Features**

- Surface mounting devices in medium power SOT-223 and SOT-89 packages
- Available in tape and reel packaging

### **Applications**

- Voltage regulation
- Relay driver
- Generic switch

#### **Description**

The STF724 and STN724 are NPN transistors manufactured using Planar technology resulting in rugged high performance devices.

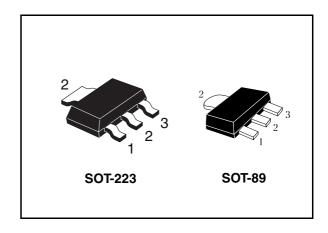


Figure 1. Internal schematic diagram

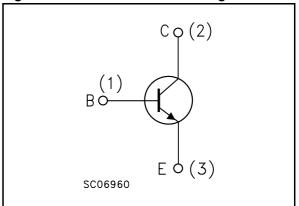


Table 1. Device summary

Order code	Marking	Package	Packaging
STF724	724	SOT-89	Tape & reel
STN724	N724	SOT-223	таре & геег

April 2008 Rev 4 1/11

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# 1 Electrical ratings

Table 2. Absolute maximum rating

Symbol	Parameter	Va	Unit	
		STF724 STN724		
V <sub>CBO</sub>	Collector-base voltage (I <sub>E</sub> = 0)	6	V	
V <sub>CEO</sub>	Collector-emitter voltage (I <sub>B</sub> = 0)	3	60	V
V <sub>EBO</sub>	Emitter-base voltage (I <sub>C</sub> = 0)	!	5	V
I <sub>C</sub>	Collector current 3		Α	
I <sub>CM</sub>	Collector peak current (t <sub>P</sub> < 5ms)	peak current (t <sub>P</sub> < 5ms)		
I <sub>B</sub>	Base current 1			Α
I <sub>BM</sub>	Base peak current (t <sub>P</sub> < 5ms)	2	2	Α
P <sub>tot</sub>	Total dissipation at T <sub>amb</sub> = 25°C	1.4	1.6	W
T <sub>stg</sub>	Storage temperature	-65 to 150		°C
T <sub>J</sub>	Max. operating junction temperature 150			°C

Table 3. Thermal data

Symbol	Parameter	Va	Unit	
		SOT-89	SOT-223	
R <sub>thj-amb</sub>	Thermal resistance junction-ambient (1) max	89	78	°C/W

<sup>1.</sup> Device mounted on PCB area of 1 cm<sup>2</sup>.

Electrical characteristics STF724 - STN724

## 2 Electrical characteristics

 $(T_{case} = 25^{\circ}C \text{ unless otherwise specified})$ 

Table 4. Electrical characteristics

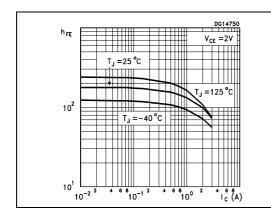
Symbol	Parameter	Test conditions		Min.	Тур.	Max.	Unit
I <sub>CES</sub>	Collector cut-off current (V <sub>BE</sub> = 0)	V <sub>CE</sub> = 60 V				10	μА
I <sub>CEO</sub>	Collector cut-off current (I <sub>B</sub> = 0)	V <sub>CE</sub> = 30 V				100	μΑ
I <sub>EBO</sub>	Emitter cut-off current (I <sub>C</sub> = 0)	V <sub>EB</sub> = 5 V				10	μΑ
V <sub>(BR)CBO</sub>	Collector-base breakdown voltage (I <sub>E</sub> = 0)	I <sub>C</sub> = 100 μA		60			V
V <sub>(BR)CEO</sub> <sup>(1)</sup>	Collector-emitter breakdown voltage (I <sub>B</sub> = 0)	I <sub>C</sub> = 10 mA		30			V
V <sub>(BR)EBO</sub>	Emitter-base breakdown voltage (I <sub>C</sub> = 0)	I <sub>E</sub> = 100 μA		5			V
V <sub>CE(sat)</sub> (1)	Collector-emitter saturation voltage		$I_B = 50 \text{ mA}$ $I_B = 100 \text{ mA}$ $I_B = 15 \text{ 0mA}$			0.4 0.7 1.1	V V V
V <sub>BE(sat)</sub> (1)	Base-emitter saturation voltage	I <sub>C</sub> = 2 A	I <sub>B</sub> = 100 mA			1.2	V
h <sub>FE</sub>	DC current gain	$I_{C} = 100 \text{ mA}$ $I_{C} = 1 \text{ A}$ $I_{C} = 3 \text{ A}$		100 80 30		300	
f <sub>T</sub>	Transition frequency	V <sub>CE</sub> = 10 V	I <sub>C</sub> = 0.1 A		100		MHz

<sup>1.</sup> Pulsed duration = 300  $\mu$ s, duty cycle  $\leq$  1.5 %

### 2.1 Electrical characteristics (curves)

Figure 2. DC Current Gain

Figure 3. DC Current Gain



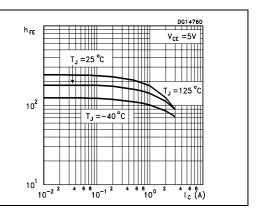
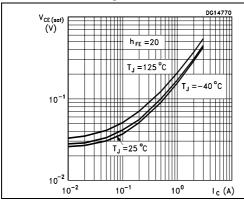


Figure 4. Collector-emitter saturation voltage

Figure 5. Base-emitter saturation voltage



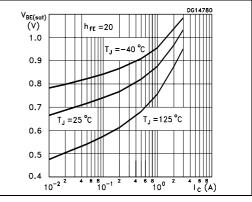
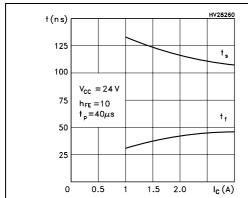
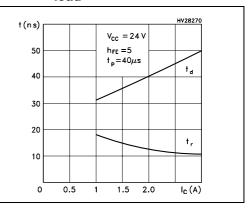


Figure 6. Switching times on resistive Figure 7. load

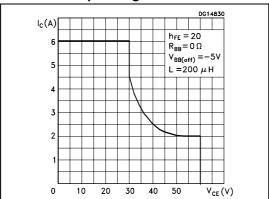
igure 7. Switching times on resistive load





Electrical characteristics STF724 - STN724

Figure 8. Reverse biased safe operating area



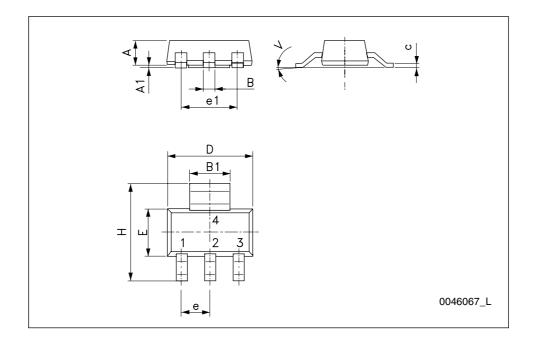
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## 3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com

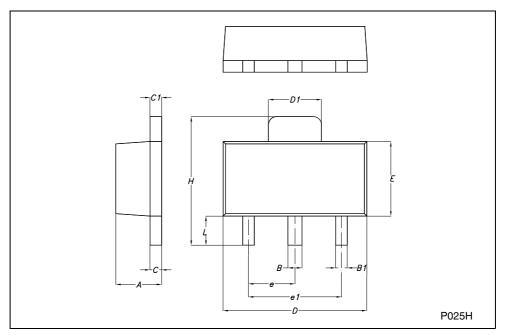
SOI	<b>L</b> _223	mechani	cal data
301	I <b>-</b> ZZ3	mechani	cai uata

DIM.	mm.					
DIIVI.	min.	typ	max.			
Α			1.80			
A1	0.02		0.1			
В	0.60	0.70	0.85			
B1	2.90	3.00	3.15			
С	0.24	0.26	0.35			
D	6.30	6.50	6.70			
е		2.30				
e1		4.60				
E	3.30	3.50	3.70			
Н	6.70	7.00	7.30			
V			10 °			



#### **SOT-89 MECHANICAL DATA**

DIM.	mm			mils		
DIWI.	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
А	1.4		1.6	55.1		63.0
В	0.44		0.56	17.3		22.0
B1	0.36		0.48	14.2		18.9
С	0.35		0.44	13.8		17.3
C1	0.35		0.44	13.8		17.3
D	4.4		4.6	173.2		181.1
D1	1.62		1.83	63.8		72.0
E	2.29		2.6	90.2		102.4
е	1.42		1.57	55.9		61.8
e1	2.92		3.07	115.0		120.9
Н	3.94		4.25	155.1		167.3
L	0.89		1.2	35.0		47.2



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Revision history STF724 - STN724

## 4 Revision history

Table 5. Document revision history

Date	Revision	Changes
29-Mar-2005	1	Initial release.
12-Oct-2005	2	Added new graphics
17-Jul-2006	3	New template
04-Apr-2008	4	SOT-223 mechanical data updated.

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